

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

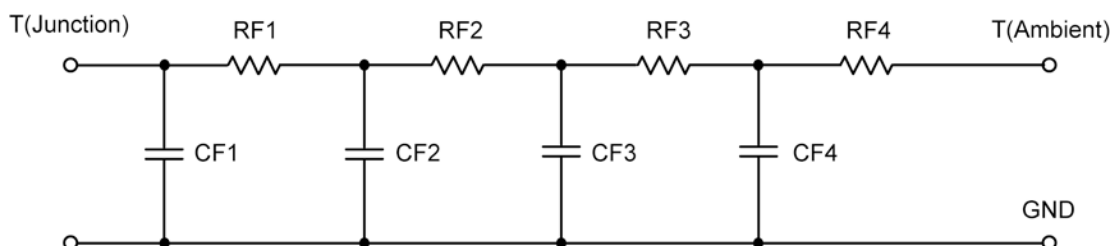
For a detailed explanation of implementing these values in P-SPIICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPIICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	5.2575	123.0684 m	N/A
RT2	56.0753	544.2755 m	N/A
RT3	10.4703	845.5248 m	N/A
RT4	9.1969	887.1313 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	7.0187 m	2.0038 m	N/A
CT2	1.2577	1.6738 m	N/A
CT3	188.2348 m	18.2963 m	N/A
CT4	34.7791 m	14.7370 m	N/A

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	6.4954	793.6689 m	N/A
RF2	8.9736	635.1155 m	N/A
RF3	11.4096	512.7679 m	N/A
RF4	54.1214	458.4477 m	N/A
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	5.1700 m	965.8802 u	N/A
CF2	17.9553 m	6.3837 m	N/A
CF3	103.7497 m	887.2094 u	N/A
CF4	1.1433	4.4512 m	N/A

Note: NA indicates not applicable

